
	<h2>SI1469DH-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1469DH-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 2.7A SC-70-6</p> <p><b>Datenblätter:</b>  <a href="#">SI1469DH-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 51985 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1469DH-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET P-CH 20V 2.7A SC-70-6
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	51985 pcs Stock
detaillierte Beschreibung	P-Channel 20V 2.7A (Tc) 1.5W (Ta), 2.78W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	1.5W (Ta), 2.78W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.7A (Tc)
Rds On (Max) @ Id, Vgs	80 mOhm @ 2A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	470pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1469DH-T1-GE3TR














SI1469DH-T1-GE3 ist neu im Original, Suche SI1469DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1469DH-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1469DH-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1470DH-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 5.1A SC-70-6</p>	 <p><b>SI1470DH-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 5.1A SC70-6</p>	 <p><b>SI1470DH-T1-E3</b> Vishay / Siliconix MOSFET N-CH 30V 5.1A SC70-6</p>	 <p><b>SI1467DH-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.7A SC-70-6</p>
 <p><b>SI1469DH-T1-E3</b> Vishay / Siliconix MOSFET P-CH 20V 2.7A SC70-6</p>	 <p><b>SI1470DH-M6TR</b> ZHIHUIDA SI1470DH-M6TR ZHIHUIDA</p>	 <p><b>SI1470DH-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 5.1A SC-70-6</p>	 <p><b>SI1469DH-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 2.7A SC-70-6</p>

### heiße Teile

Mehr

 SI1422DH-T1-GE3	 SI1422DH-T1-GE3	 SI1424EDH-T1-GE3	 SI1424EDH-T1-GE3	 SI1426DH-T1-E3
 SI1426DH-T1-E3	 SI1426DH-T1-GE3	 SI1426DH-T1-GE3	 SI1427EDH-T1-GE3	 SI1427EDH-T1-GE3
 SI1428EDH-T1-GE3	 SI1428EDH-T1-GE3	 SI1433DH-T1	 SI1433DH-T1-E3	 SI1433DH-T1-E3
 SI1433DH-T1-GE3	 SI1433DH-T1-GE3	 SI1441EDH-T1-GE3	 SI1441EDH-T1-GE3	 SI1442DH-T1-GE3
 SI1442DH-T1-GE3	 SI1443EDH-T1-GE3	 SI1443EDH-T1-GE3	 SI14467DH-T1-GE3	 SI14467DH-T1-GE3
 SI1469DH-T1-GE3	 SI1470DH-M6TR	 SI1470DH-T1-GE3	 SI1470DH-T1-GE3	 SI1471DH-T1
 SI1471DH-T1-E3	 SI1471DH-T1-E3	 SI1471DH-T1-GE3	 SI1471DH-T1-GE3	 SI1472DH-T1-E3
 SI1472DH-T1-E3	 SI1473DH-T1-E3	 SI1473DH-T1-E3	 SI1473DH-T1-GE3	 SI1473DH-T1-GE3
 SI1488DH-T1-GE3	 SI1488DH-T1-GE3	 SI1489EDH-T1-GE3	 SI1489EDH-T1-GE3	 SI1499DH-T1-GE3
 SI1499DH-T1-GE3	 SI1501DL	 SI1501DL-T1	 SI1501DL-T1-E3	 SI1501DL-T1-GE3

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